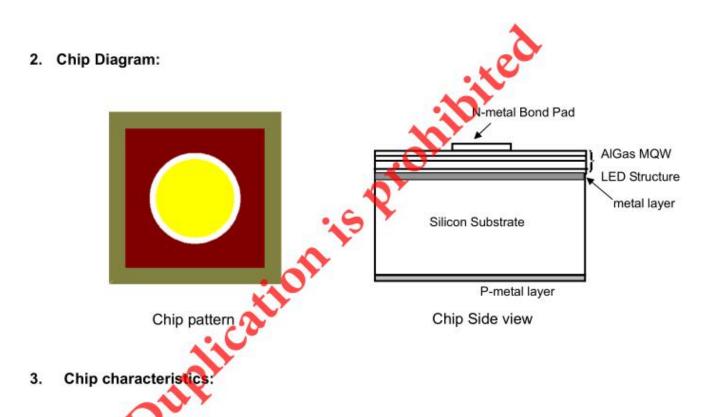
# IN-F10IR

## **Descriptions:**

F10IR is an Infra-red LED chip made from MOCVD process and bonded with Silicon. It is fabricated by the HPO's proprietary metal Bonding mechanism, F10IR is featured by homogeneous and high light output at top side with superior beam pattern. Excellent performance under sunlight and reliable life-long stability makeF10IR ideal for IrDA, Encoder, data communication applications.



Substrate	Si		
Emitting material	AlGaAs		
p-pad electrode	Au-alloy		
n-pad electrode	Au-alloy		
Chip size	217±25um × 217±25um		
Chip thickness	125±25um		
Pad Diameter	92±15um		

# 4. Electrical and Optical Characteristics(Ta=25°C):

Parameter	Condition *1	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I <sub>F</sub> =20mA	V <sub>F1</sub>	1.3	1.6	1.8	V
Threshold voltage	I==10uA	V <sub>F3</sub>	1.0	1.1	1.3	V
Reverse current	V <sub>R</sub> =5V	I <sub>R</sub>	-	-	10.0	uA
Peak wavelength	I <sub>F</sub> =20mA	λ <sub>p</sub>	840	-	860	nm
Half width *2	I=20mA	Δλ	-	30	-	nm
Radiant Power *3	I⊧=20mA	Ро	2	60	-	mW

### Note:

- \*1 IF : DC Forward current VR : Reverse voltage
- Value of Half width is only for reference
- Radiant Power is measured by HPO's equipment on bare chips.
- 4 Characteristic curves are measured on standard TO-39 package type without encapsure.

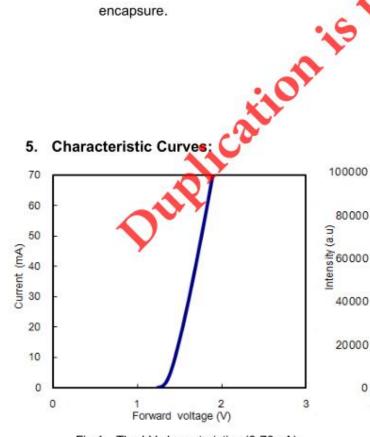


Fig.1 The I-V characteristics (0-70mA)

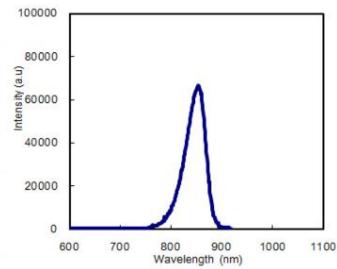


Fig.2 The EL spectrum

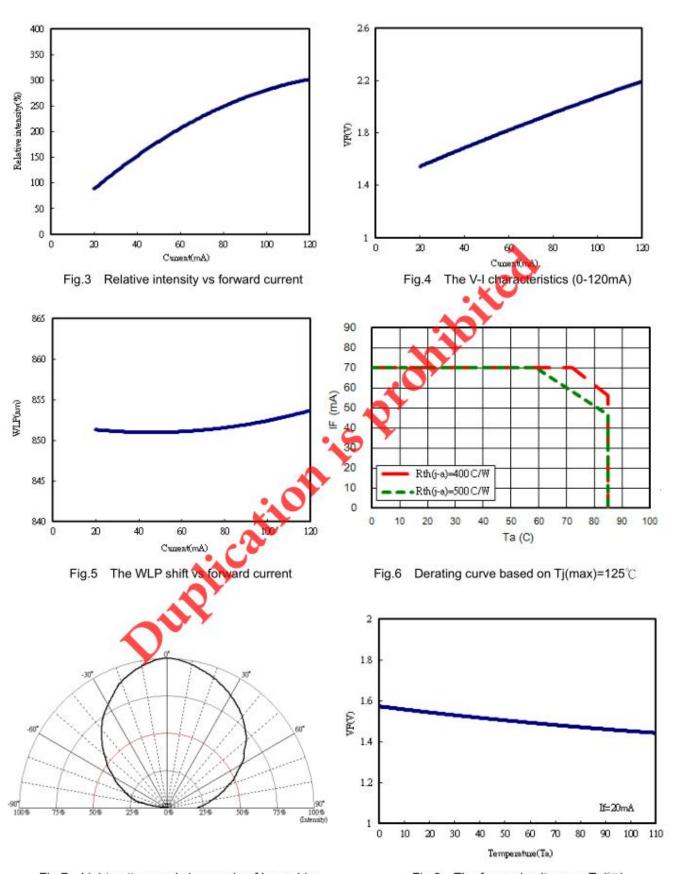
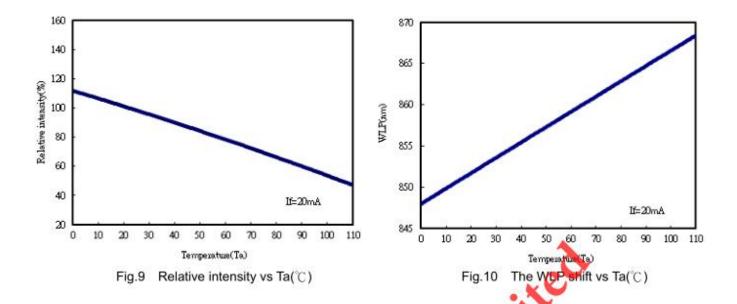


Fig.7 Light pattern and view angle of bare chip

Fig.8 The forward voltage vs Ta(℃)



# 6. Absolute Maximum Ratings(Ta=25°C):

Parameter	Symbol	Condition	Rating	
DC Forward Current	le	<b>Ta=25℃</b>	≤30mA	
Peak Pulsing Current	lpeak 4	/10 duty cycle @ 1kHz (T <sub>i</sub> ≦65℃)	≦70mA	
Reverse Voltage	VR	Ta=25°C	≤10V	
Operating Temperature Range	FOP	-	-40°C to +85°C	
Storage Temperature Bond	, , , , , , , , , , , , , , , , , , ,	Chip-on-tape/storage	+5°C to +30°C	
Storage Temperature Range	Tstg	Chip-on-tape/transportation	-20°C to +65°C	
LED Junction Temperature	Tį		≦125°C	
Temperature during Packaging	(E)		280°C (<10sec)	

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Metal Core Printed Circuit Board(MCPCB) without an encapsulant. Stress in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.